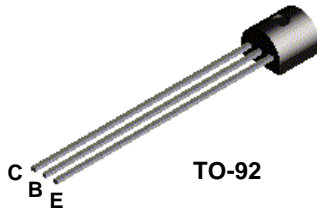
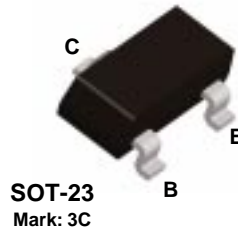


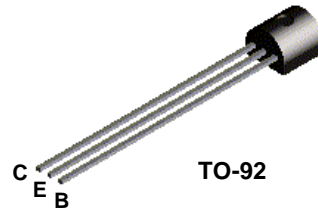
## MPS5179



## MMBT5179



## PN5179



### NPN RF Transistor

This device is designed for use in low noise UHF/VHF amplifiers with collector currents in the 100  $\mu$ A to 30 mA range in common emitter or common base mode of operation, and in low frequency drift, high output UHF oscillators. Sourced from Process 40.

#### Absolute Maximum Ratings\*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	12	V
V <sub>CBO</sub>	Collector-Base Voltage	20	V
V <sub>EBO</sub>	Emitter-Base Voltage	2.5	V
I <sub>C</sub>	Collector Current - Continuous	50	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units
		PN/MPS5179	*MMBT5179	
P <sub>D</sub>	Total Device Dissipation	350	225	mW
	Derate above 25°C	2.8	1.8	mW/°C
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	357	556	°C/W

\*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

**NPN RF Transistor**  
(continued)

**MPS5179 / MMBT5179 / PN5179**

**Electrical Characteristics**

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
--------	-----------	-----------------	-----	-----	-------

**OFF CHARACTERISTICS**

$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage*	$I_C = 3.0 \text{ mA}, I_B = 0$	12		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 1.0 \text{ } \mu\text{A}, I_E = 0$	20		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10 \text{ } \mu\text{A}, I_C = 0$	2.5		V
$I_{CBO}$	Collector Cutoff Current	$V_{CB} = 15 \text{ V}, I_E = 0$ $V_{CB} = 15 \text{ V}, T_A = 150^\circ\text{C}$		0.02 1.0	$\mu\text{A}$ $\mu\text{A}$

**ON CHARACTERISTICS**

$h_{FE}$	DC Current Gain	$I_C = 3.0 \text{ mA}, V_{CE} = 1.0 \text{ V}$	25	250	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$		0.4	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$		1.0	V

**SMALL SIGNAL CHARACTERISTICS**

$f_T$	Current Gain - Bandwidth Product	$I_C = 5.0 \text{ mA}, V_{CE} = 6.0 \text{ V},$ $f = 100 \text{ MHz}$	900	2000	MHz
$C_{cb}$	Collector-Base Capacitance	$V_{CB} = 10 \text{ V}, I_E = 0,$ $f = 0.1 \text{ to } 1.0 \text{ MHz}$		1.0	pF
$h_{fe}$	Small-Signal Current Gain	$I_C = 2.0 \text{ mA}, V_{CE} = 6.0 \text{ V},$ $f = 1.0 \text{ kHz}$	25	300	
$r_b' C_c$	Collector Base Time Constant	$I_C = 2.0 \text{ mA}, V_{CB} = 6.0 \text{ V},$ $f = 31.9 \text{ MHz}$	3.0	14	ps
NF	Noise Figure	$I_C = 1.5 \text{ mA}, V_{CE} = 6.0 \text{ V},$ $R_S = 50 \Omega, f = 200 \text{ MHz}$		5.0	dB

**FUNCTIONAL TEST**

$G_{pe}$	Amplifier Power Gain	$V_{CE} = 6.0 \text{ V}, I_C = 5.0 \text{ mA},$ $f = 200 \text{ MHz}$	15		dB
$P_O$	Power Output	$V_{CB} = 10 \text{ V}, I_E = 12 \text{ mA},$ $f \geq 500 \text{ MHz}$	20		mW

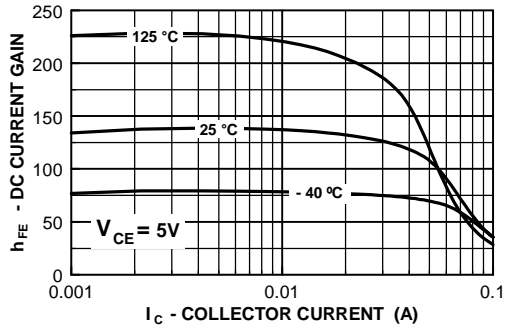
\*Pulse Test: Pulse Width  $\leq 300 \text{ } \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

**Spice Model**

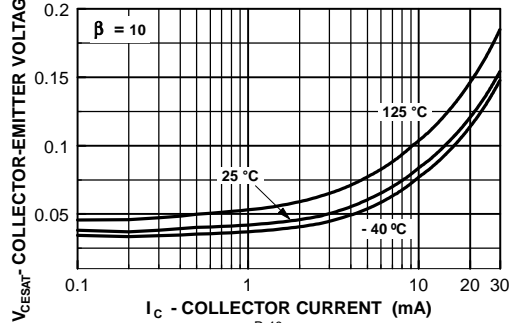
NPN (Is=69.28E-18 Xti=3 Eg=1.11 Vaf=100 Bf=282.1 Ne=1.177 Ise=69.28E-18 Ikf=22.03m Xtb=1.5 Br=1.176 Nc=2 Isc=0 Ikr=0 Rc=4 Cjc=1.042p Mjc=.2468 Vjc=.75 Fc=.5 Cje=1.52p Mje=.3223 Vje=.75 Tr=1.588n Tf=135.6p Itf=.27 Vtf=10 Xtf=30 Rb=10)

DC Typical Characteristics

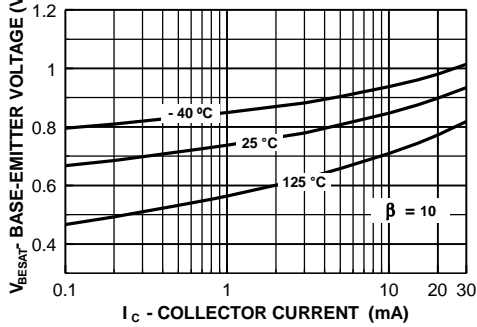
DC Current Gain vs Collector Current



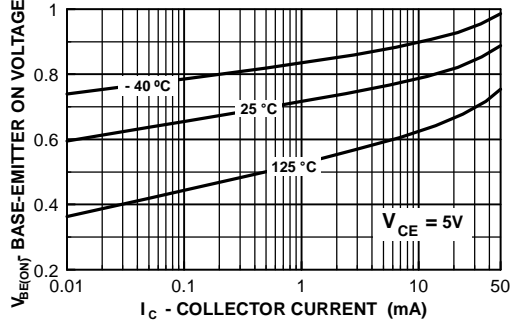
Collector-Emitter Saturation Voltage vs Collector Current



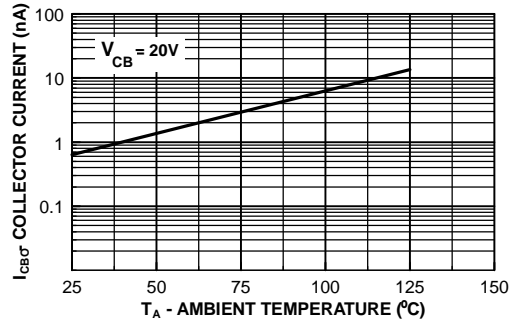
Base-Emitter Saturation Voltage vs Collector Current



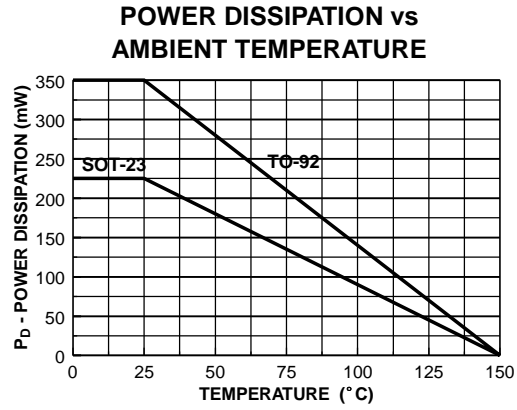
Base-Emitter ON Voltage vs Collector Current



Collector-Cutoff Current vs Ambient Temperature



AC Typical Characteristics



Test Circuit

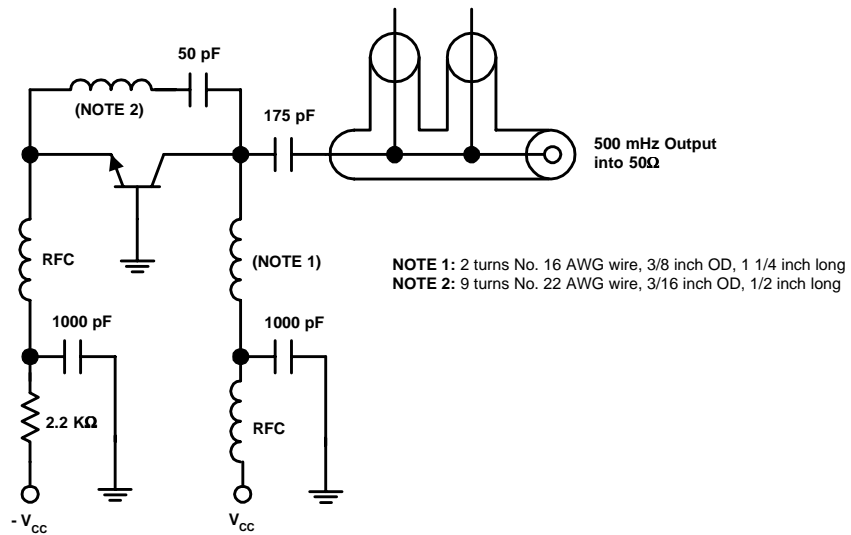


FIGURE 1: 500 MHz Oscillator Circuit